

L2720D

LOW DROP DUAL POWER OPERATIONAL AMPLIFIER

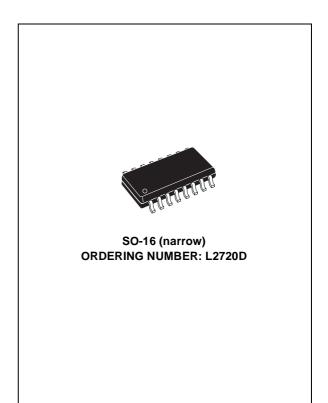
- OUTPUT CURRENT TO 1 A
- OPERATES AT LOW VOLTAGES
- SINGLE OR SPLIT SUPPLY
- LARGE COMMON-MODE AND DIFFERENTIAL MODE RANGE
- LOW INPUT OFFSET VOLTAGE
- GROUND COMPATIBLE INPUTS
- LOW SATURATION VOLTAGE
- THERMAL SHUTDOWN
- CLAMP DIODE

DESCRIPTION

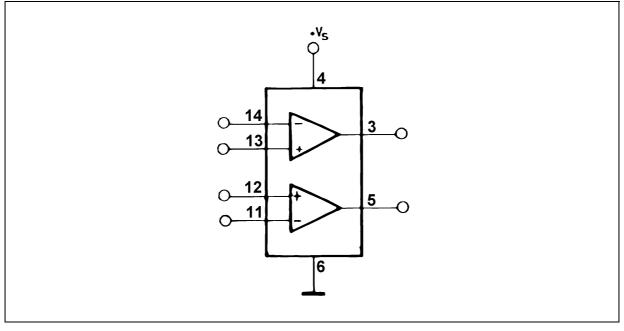
The L2720D is a monolithic integrated circuits in SO-16 package, intended for use as power operational amplifiers in a wide range of applications including servo amplifiers and power supplies.

It is particularly indicated for driving, inductive loads, as motor and finds applications in compact-disc VCR automotive, etc.

The high gain and high output power capability provide superior performance whatever an operational amplifier/power booster combination is required.



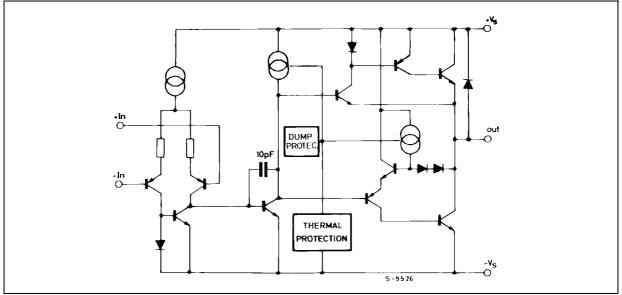
BLOCK DIAGRAM



L2720D

PIN CONNECTION (Top view) N.C. 16 N.C. 11 1 N.C. 15 N.C. 2 OUTPUT 1 14 |] INPUT- 1 Vs 13 INPUT+ 1 OUTPUT 2 12 INPUT+ 2 GND 11 INPUT- 2 6 N.C. N.C. 10 N.C. 9 N.C. 8

SCHEMATIC DIAGRAM (one section)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
VS	Supply Voltage	28	V	
Vs	Peak Supply Voltage (50ms)	50	V	
Vi	Input Voltage	Vs		
Vi	Differential Input Voltage	±Vs		
۱ _۵	DC Output Current	1	А	
۱ _p	Peak Output Current (non repetitive)	1.5	А	
P _{tot}	Power Dissipation at T _{amb} = 50°C	800	mW	
T _{op}	Operating Temperature	– 40 to 85	°C	
T _{stg} , T _j	Storage and Junction Temperature	– 40 to 150	°C	

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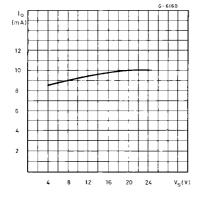
THERMAL DATA

Symbol	Parameter	Value	Unit
R _{th j-amb}	Thermal Resistance Junction to ambient Typ.	95	°C/W

ELECTRICAL CHARACTERISTICS ($V_s = 24V$, $T_{amb} = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vs	Single Supply Voltage		4		28	V
Vs	Split Supply Voltage		± 2		± 14	V
Is	Quiescent Drain Current	$V_0 = \frac{V}{2}$				
		$V_{s} = 24V$ $V_{s} = 8V$		10 9	15 15	mA mA
I _b	Input Bias Current			0.2	1	μΑ
Vos	Input Offset Voltage				10	mV
l _{os}	Input Offset Current				100	nA
SR	Slew Rate			2		V/µs
В	Gain-bandwidth Product			1.2		MHz
Ri	Input Resistance		500			kΩ
Gv	O.L. Voltage Gain	f = 100Hz f = 1kHz	70	80 60		dB
e _N	Input Noise Voltage	B = 22Hz to 22kHz		10		μV
I _N	Input Noise Voltage			200		pА
CMR	Common Mode Rejection	f = 1kHz	66	84		dB
SVR	Supply Voltage Rejection		60	70 75 80		dB
V _{DROP} (H)	Drop voltage high	$V_s = \pm 2.5V$ to $\pm 12V$ $I_p = 100mA$ $I_p = 500mA$		0.7 1	1.5	V
V _{DROP} (L)	Drop voltage low	$V_s = \pm 2.5V$ to $\pm 12V$ $I_p = 100mA$ $I_p = 500mA$		0.3 0.5	1	V
Cs	Channel Separation	$ f = 1 KHz; V_s = 24V \\ R_L = 10\Omega; V_s = 6V \\ G_v = 30 dB $		60 60		dB
T _{sd}	Thermal Shutdown Junction Temperature			145		°C





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Figure 2. Open Loop Gain vs. Frequency

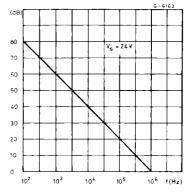


Figure 3. Common Mode Rejection vs. Frequency

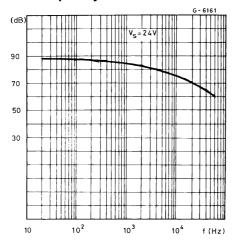


Figure 4. Output Swing vs. Load Current $(V_S = \pm 5V)$.

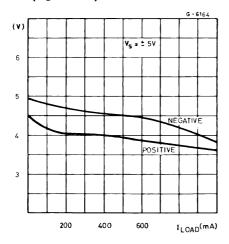
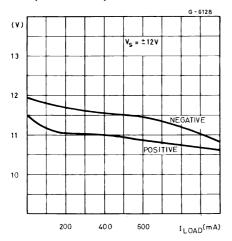


Figure 5. Output Swing vs. Load Current $(V_S = \pm 12V)$.



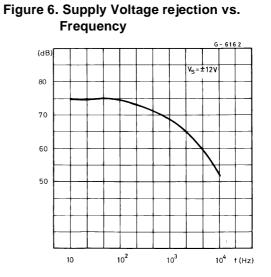
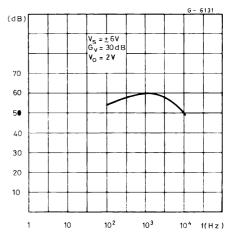
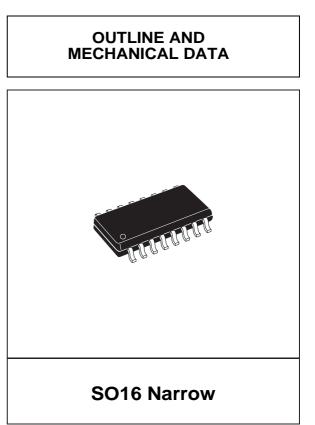


Figure 7. Channel Separation vs. Frequency

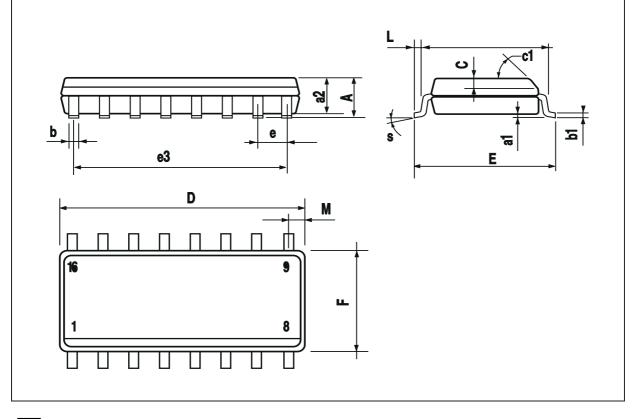


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DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.009	
a2			1.6			0.063	
b	0.35		0.46	0.014		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.020		
c1			45° (typ.)			
D (1)	9.8		10	0.386		0.394	
Е	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		8.89			0.350		
F (1)	3.8		4	0.150		0.157	
G	4.6		5.3	0.181		0.209	
L	0.4		1.27	0.016		0.050	
М			0.62			0.024	
S	8°(max.)						



(1) D and F do not include mold flash or protrusions. Mold flash or potrusions shall not exceed 0.15mm (.006inch).



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